# **BD180G**

# Plastic Medium-Power Silicon PNP Transistor

This device is designed for use in 5.0 to 10 Watt audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

### Features

- High DC Current Gain
- BD180 is complementary with BD179
- These Devices are Pb-Free and are RoHS Compliant\*

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	80	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	80	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current	۱ <sub>C</sub>	1.0	Adc
Base Current	I <sub>B</sub>	2.0	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	30 240	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL CHARACTERISTICS

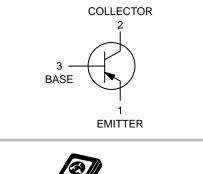
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\thetaJC}$	4.16	°C/W



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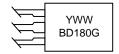
http://onsemi.com

## 3.0 AMPERES POWER TRANSISTORS PNP SILICON 80 VOLTS, 30 WATTS





#### MARKING DIAGRAM



Y	= Year
WW	= Work Week
BD180	= Device Code
G	= Pb-Free Package

#### **ORDERING INFORMATION**

Device	Package	Shipping
BD180G	TO-225 (Pb-Free)	500 Units/Box

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Characteristic	Symbol	Min	Мах	Unit
Collector–Emitter Sustaining Voltage (Note 1) $(I_C = 0.1 \text{ Adc}, I_B = 0)$	V <sub>(BR)CEO</sub>	80	_	Vdc
Collector Cutoff Current ( $V_{CB} = 80 \text{ Vdc}, I_E = 0$ )	I <sub>CBO</sub>	-	1.0	mAdc
Emitter Cutoff Current ( $V_{BE} = 5.0 \text{ Vdc}, I_C = 0$ )	I <sub>EBO</sub>	_	1.0	mAdc
DC Current Gain ( $I_C = 0.15 \text{ A}, V_{CE} = 2.0 \text{ V}$ ) ( $I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ )	h <sub>FE</sub>	40 15	250 -	-
Collector–Emitter Saturation Voltage (Note 1) $(I_{C} = 1.0 \text{ Adc}, I_{B} = 0.1 \text{ Adc})$	V <sub>CE(sat)</sub>	_	0.8	Vdc
Base–Emitter On Voltage (Note 1) ( $I_C = 1.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$ )	V <sub>BE(on)</sub>	_	1.3	Vdc
Current–Gain – Bandwidth Product ( $I_C = 250 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ MHz}$ )	fT	3.0	_	MHz

1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

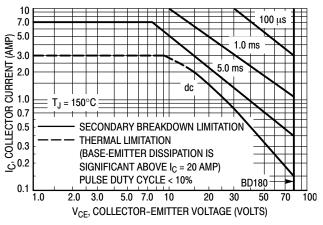


Figure 1. Active Region Safe Operating Area

The Safe Operating Area Curves indicate  $I_C-V_{CE}$  limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum  $T_J$ , power–temperature derating must be observed for both steady state and pulse power conditions.

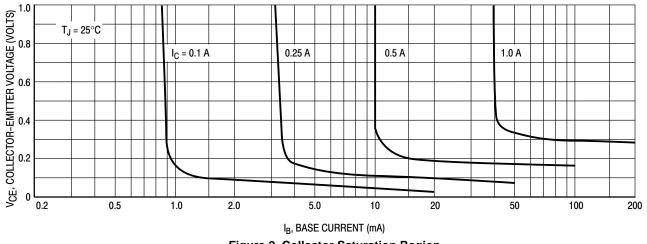
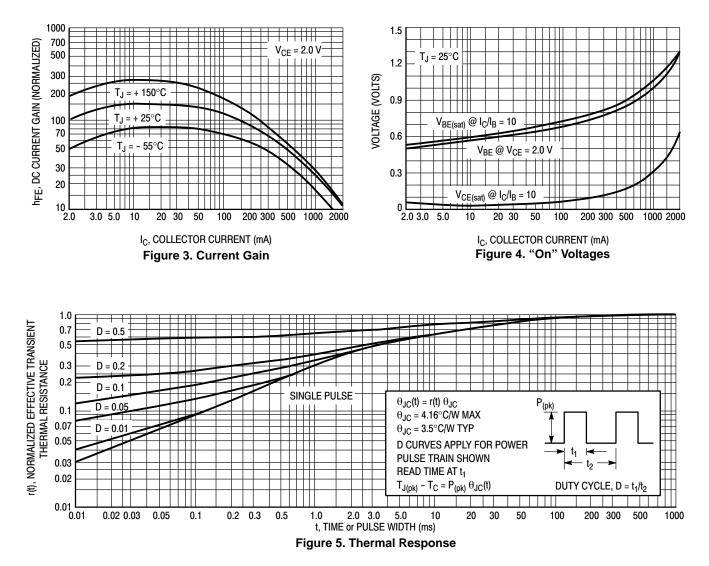


Figure 2. Collector Saturation Region

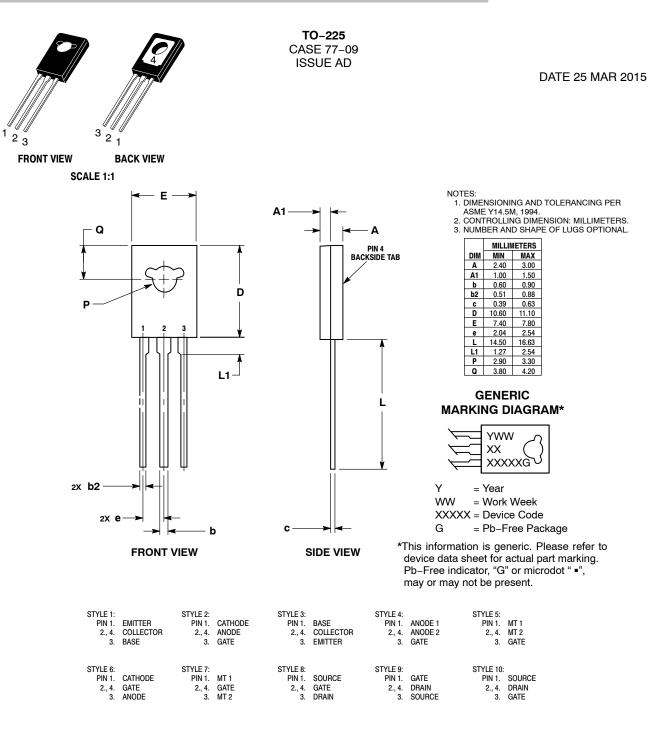
## **BD180G**



MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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